

Vishay Semiconductors

Fast Avalanche Sinterglass Diode

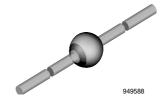
Features

- · Glass passivated junction
- · Hermetically sealed package
- · Low reverse current
- · Soft recovery characteristics
- Lead (Pb)-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

Applications

Fast rectification and switching diode for example for TV-line output circuits and switch mode power supply





Mechanical Data

Case: SOD-64 Sintered glass case

Terminals: Plated axial leads, solderable per

MIL-STD-750, Method 2026

Polarity: Color band denotes cathode end

Mounting Position: Any Weight: approx. 858 mg

Parts Table

Part	Type differentiation	Package
BYW72	V _R = 200 V; I _{FAV} = 3 A	SOD-64
BYW73	V _R = 300 V; I _{FAV} = 3 A	SOD-64
BYW74	V _R = 400 V; I _{FAV} = 3 A	SOD-64
BYW75	V _R = 500 V; I _{FAV} = 3 A	SOD-64
BYW76	V _R = 600 V; I _{FAV} = 3 A	SOD-64

Absolute Maximum Ratings

T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Part	Symbol	Value	Unit
Reverse voltage = Repetitive peak reverse voltage	see electrical characteristics	BYW72	$V_R = V_{RRM}$	200	V
		BYW73	$V_R = V_{RRM}$	300	V
		BYW74	$V_R = V_{RRM}$	400	V
		BYW75	$V_R = V_{RRM}$	500	V
		BYW76	$V_R = V_{RRM}$	600	V
Peak forward surge current	t _p = 10 ms, half sinewave		I _{FSM}	100	Α
Repetitive peak forward current			I _{FRM}	15	Α
Average forward current			I _{FAV}	3	Α
Junction and storage temperature range			$T_j = T_{stg}$	- 55 to + 175	°C
Non repetitive reverse avalanche energy	I _{(BR)R} = 0.4 A		E _R	10	mJ

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Maximum Thermal Resistance

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Value	Unit
Junction ambient	I = 10 mm, T _L = constant	R_{thJA}	25	K/W
	on PC board with spacing 25 mm	R _{thJA}	70	K/W

Electrical Characteristics

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Forward voltage	I _F = 3 A	V _F		0.95	1.1	V
Reverse current	$V_R = V_{RRM}$	I _R		1	5	μА
	$V_R = V_{RRM}$, $T_j = 150 ^{\circ}C$	I _R		60	150	μΑ
Reverse recovery time	$I_F = 0.5 \text{ A}, I_R = 1 \text{ A}, I_R = 0.25 \text{ A}$	t _{rr}			200	ns

Typical Characteristics (Tamb = 25 °C unless otherwise specified)

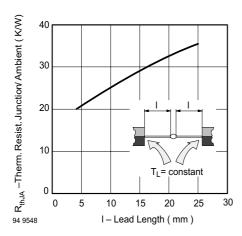


Figure 1. Max. Thermal Resistance vs. Lead Length

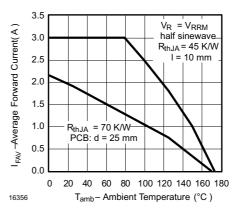


Figure 3. Max. Average Forward Current vs. Ambient Temperature

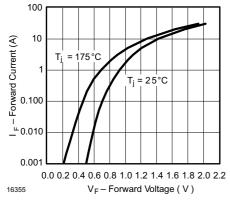


Figure 2. Forward Current vs. Forward Voltage

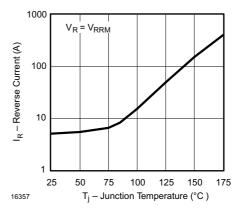
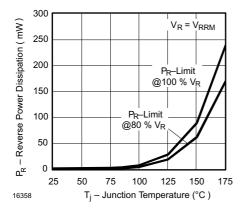
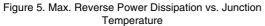


Figure 4. Reverse Current vs. Junction Temperature



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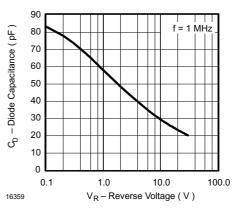


Figure 6. Diode Capacitance vs. Reverse Voltage

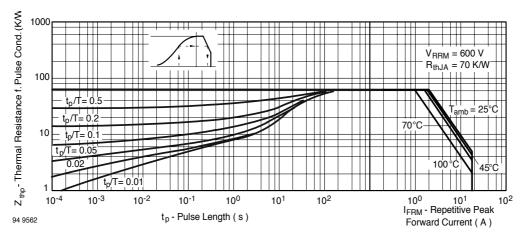
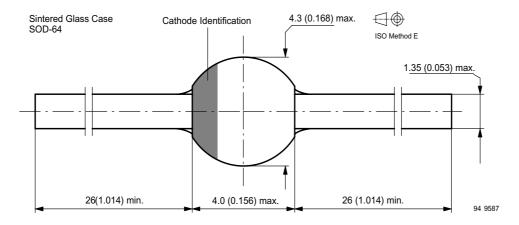


Figure 7. Thermal Response

Package Dimensions in mm (Inches)



BYW72 / 73 / 74 / 75 / 76

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Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

> We reserve the right to make changes to improve technical design and may do so without further notice.

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